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AMENDMENT TRANSMITTAL LETTER						Docket No. FIS920030286US1	
Application No.		Filing Date		Examiner	7 11 0 111		
10/605,889		11/04/03		Long Pham	m 2814		
Invention: OXIDA	hael P. Belyar TION METHOI TURE FORMI	O FOR ALTER		STRUCTURE AND	CMOS T	RANSISTOR	
	TC	THE COMMI	ISSIONER FO	OR PATENTS			
Transmitted here	with is an ame	ndment in the	above-identif	ed application.			
The fee has been	calculated and	d is transmitte	d as shown b	elow.			
		CLAIM	S AS AMENI	DED			
	Claims Remaining After Amendment	Highest Number Previously Paid	Number Extra Claims Present	Rate			
Total Claims	20	30					
Independent Claims	2	3					
A duplicate of A check in the Payment by The Director as described X Credit ar	e specify):  ONAL FEE FO  I fee is required to the second of this she credit card. For is hereby authorized below. A dupling overpayment additional filing.	or this amerount Noet is enclosed orized to charglicate copy of the	ndment. ir to cover is attached. ge and credit this sheet is e	Small Entity  the amount of \$  the filing fee is enclo  Deposit Account No  nclosed.  ees required under 37  Dated:	. <b>09-</b>		
I hereby certify that this sufficient postage as Fi 1450, on the date show Dated: May 16, 2005	s correspondence is rst Class Mail, in ar rn below. Signature		ensmitted to the U	SPTO or deposited with the prefer for Parents, P.O. Box (Daryl K. Neff)	e U.S. Postal 1450, Alexar	Service with ndria, VA 22313-	

Increase certify that the correspondence is being facsimile transmitted to the USPTO or deposited with the United States Postal Service with sufficient postage as first of assimilation an envelope addressed to: MS Amendment, Commissioner for Patents, Alexandria, VA 22313-1450 on this date: May 16, 2005

Name of Depositor: Daryl K. Neff Signature

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE				
In re application of: Michael P. Belyansky, et al.	Date: May 16, 2005			
Serial Number: 10/605,889	Examiner: Long Pham			
Filed: November 4, 2003	Group Art Unit: 2814			
Title: OXIDATION METHOD FOR ALTERING A FILM STRUCTURE AND CMOS TRANSISTOR STRUCTURE FORMED THEREWITH	IBM Corporation D/18G, B/300, Zip 482 2070 Route 52 Hopewell Junction, NY 12533-6531			

## AMENDMENT

MS Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

In response to the Office Action dated February 16, 2005, Applicants submit the following amendments and remarks.